

ISSUED 07/02/2007

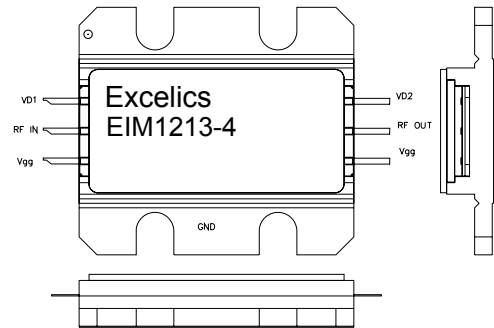
12.75 – 13.25GHz Multi-Stage Power Amplifier

FEATURES

- 12.75– 13.25GHz Operating Frequency Range
- 35.5dBm Output Power at 1dB Compression
- 27.0 dB Typical Power Gain @1dB gain compression
- -45dBc Typical OIM3 @ each tone Pout 22dBm

APPLICATIONS

- Point-to-point and point-to-multipoint radio
- Military Radar Systems



Caution! ESD sensitive device.

ELECTRICAL CHARACTERISTICS (Tb = 25 °C, 50 ohm, VD1=7V, VD2=10V, Vgg=-5V)

SYMBOL	PARAMETER/TEST CONDITIONS	MIN	TYP	MAX	UNITS
F	Operating Frequency Range	12.75		13.25	GHz
P1dB	Output Power at 1dB Gain Compression	34.5	35.5		dBm
G1dB	Gain @1dB gain compression	23	27		dB
OIMD3	Output 3 rd Order Intermodulation Distortion @Δf=10MHz, Each Tone Pout 22dBm	-43	-45		dBc
Input RL	Input Return Loss		-12	-8	dB
Output RL	Output Return Loss		-15	-10	dB
VD1	Drain Supply Voltage 1		7		V
VD2	Drain Supply Voltage 2		10		V
IDQ1	Quiescent Drain Current 1		380		mA
IDQ2	Quiescent Drain Current 2		1900	2300	mA
Vgg	Gate Supply Voltage		-5		V
Rth	Thermal Resistance		3		°C/W
Tb	Operating Base Plate Temperature	- 30		+ 80	°C

Note: Turn on/off sequence is required: ---to turn on: apply -5V on both Vgg first, then +7V and +10V.
 ---to turn off: turn +7V and +10V off first, then turn -5V off

Specifications are subject to change without notice.

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EIM1213-4

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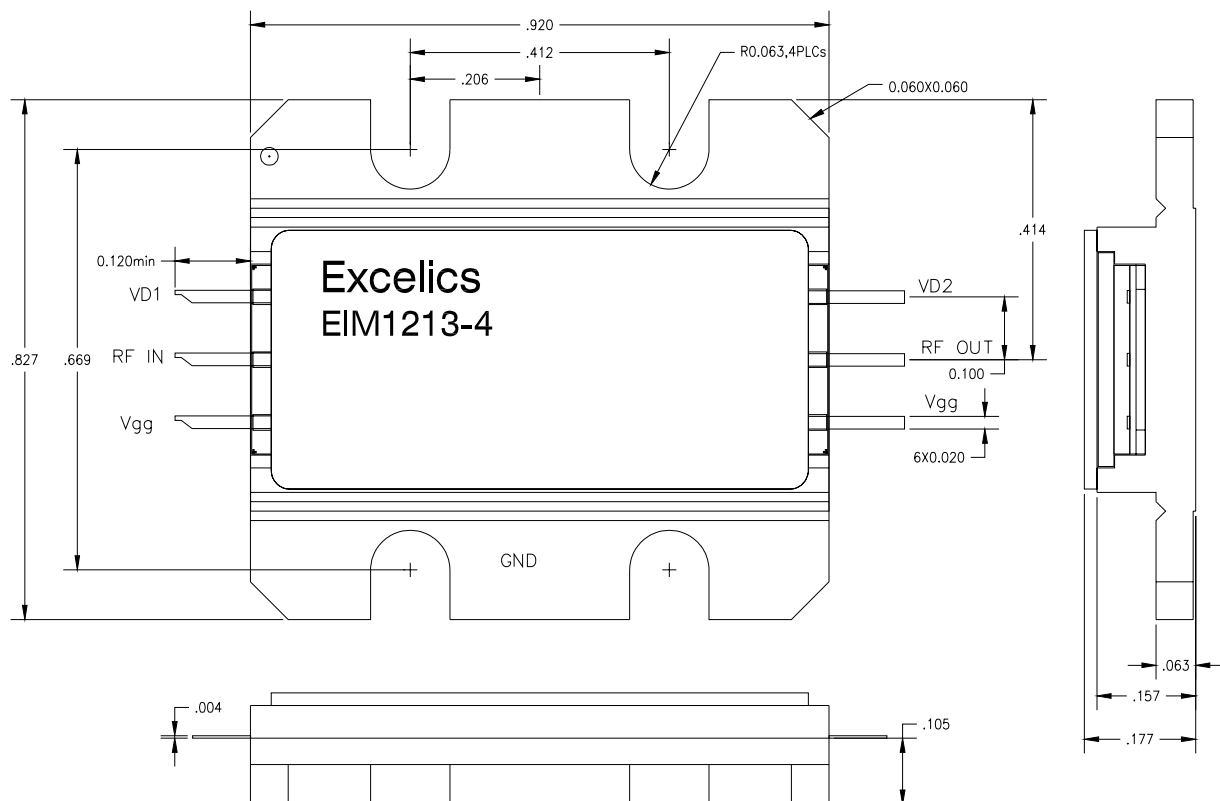
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MAXIMUM RATINGS @25°C^{1,2}

SYMBOL	CHARACTERISTIC	ABSOLUTE	CONTINUOUS ^{1,2}
V _{D1}	Drain Supply Voltage 1	12V	8V
V _{D2}	Drain Supply Voltage 2	14V	10V
V _{gg}	Gate Supply Voltage	-10V	-6 V
I _{gg}	Gate Current	150mA	50 mA
P _{IN}	Input Power	20dBm	@ 3dB compression
T _{CH}	Channel Temperature	175°C	150°C
T _{STG}	Storage Temperature	-65/175°C	-65/150°C
P _T	Total Power Dissipation	42W	35W

Notes: 1. Operating the device beyond any of the above rating may reduce MTTF and cause permanent damage.
 2. Bias conditions must also satisfy the following equation $V_{dd} \cdot I_{dd} < (T_{CH} - T_b) / R_{TH}$

Package Dimension and Pin Assignment



Dimensions are in inches

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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